NPN Epitaxial Planar Silicon Transistor

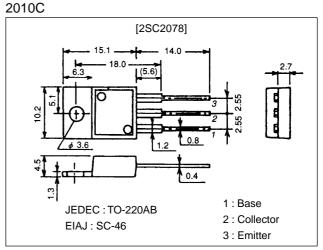


2SC2078

27MHz RF Power Amplifier Applications

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		80	V
Collector-to-Emitter Voltage	VCER	R _{BE} =150Ω	75	V
Emitter-to-Base Voltage	V _{EBO}		5	V
Collector Current	۱ _C		3	A
Collector Current (Pulse)	ICP		5	A
Collector Dissipation	PC		1.2	W
		Tc=50°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings		
		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0		10	μA
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0		10	μA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =0.5A 25*		200*	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.1A 100	150		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz	45	60	pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =1A, I _B =0.1A	0.15	0.6	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =1A, I _B =0.1A	0.9	1.2	V
* : The 2SC2078 are classified by 0.5A here as f	follows : 2	5 B 50 40 C 80 60 D 120 100 E 2	200		

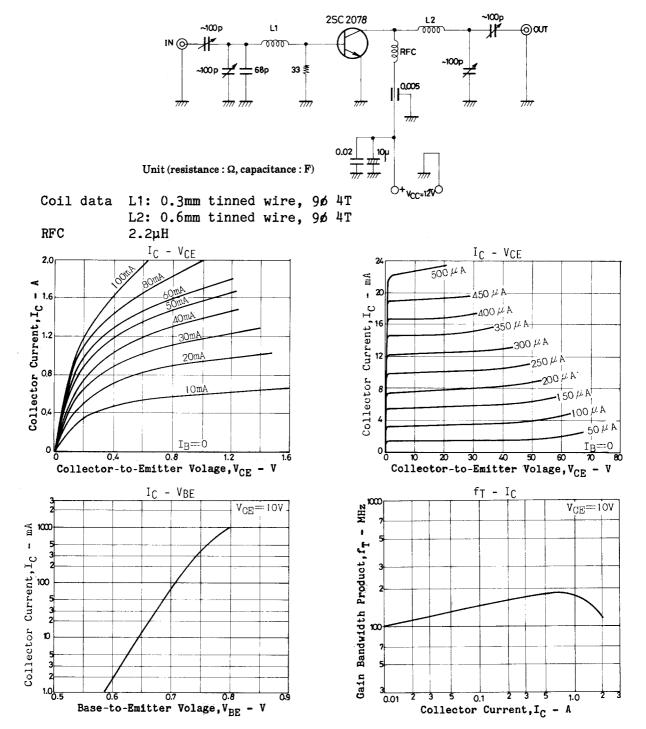
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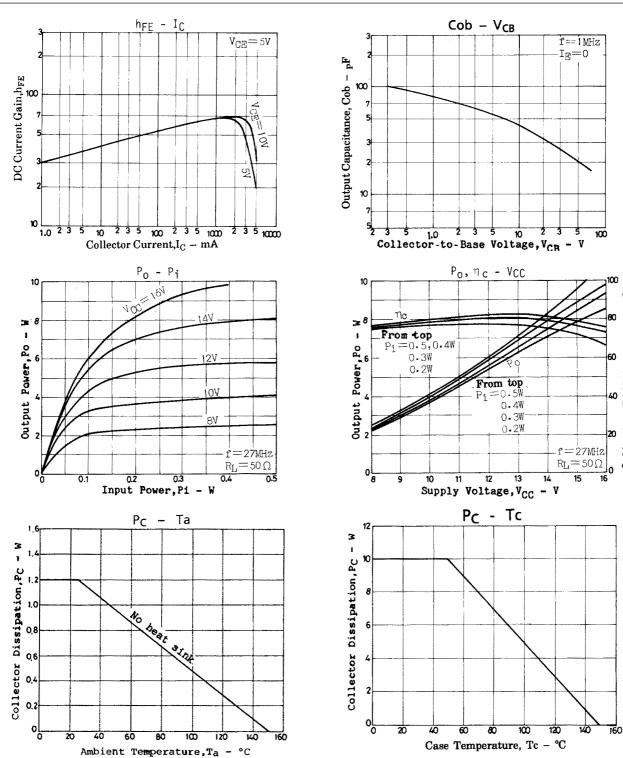
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Base Saturation Voltage	V(BR)CBO	I _C =100µA, I _B =0	80			V
Collector-to-Emitter Saturation Voltage	V(BR)CER	$I_{C}=1mA$, $R_{BE}=150\Omega$	75			V
Emitter-to-Base Saturation Voltage	V(BR)EBO	I _E =100μA, I _C =0	5			V
[At specified test circuit]		•				
Output Power	PO	V _{CC} =12V, f=27MHz, Pi=0.2W	4.0			W
Power Efficiency	η		60			%

27MHz Output Power Test Circuit





Collector Efficiency, na - \$

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